# AN6553, AN6553S

# **Dual Operational Amplifiers**

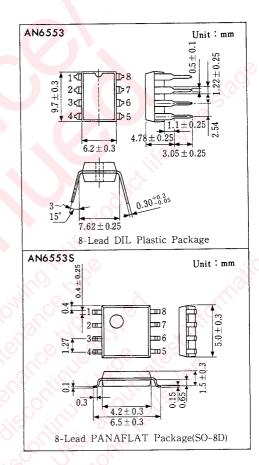
#### Outline

The AN6553 and the AN6553S are dual operational Amplifiers with phase compensation circuits built-in.

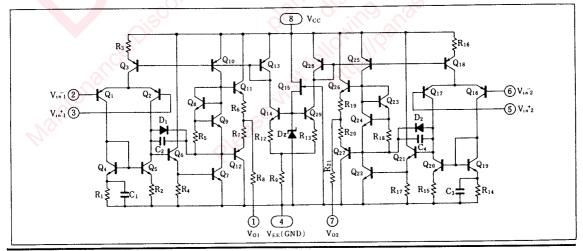
They are suited for application to various electronic circuits such as active filters audio preamplifiers.

#### **■** Features

- Phase compensation circuit
- High gain, low noise
- Output short-circuit protection
- Slew rate : 2.0 V/ $\mu$ s typ.



## Schematic Diagram





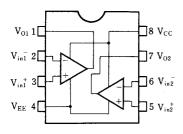
### Absolute Maximum Ratings $(Ta=25^{\circ}C)$

Item			Symbol	Rating	Unit	
	Supply Vo.	Itage	$V_{cc}$	±18	V	
Voltage	Differentia	l Input Voltage	V <sub>ID</sub>	±30	V	
	Common-M	Iode Input Voltage	V <sub>ICM</sub>	±15	V	
Power Dissipa	AN6553		D	500	***	
TOWEI DISSIPA	AN6553S		$P_{D}$	360	mW	
Temperature	Operating Ambien	t Temperature	$T_{\sf opr}$	$-20 \sim +75$	$^{\circ}$	
	Storage Temperature	AN6553	T	-55~+150	°C	
	Storage reinperature	AN6553S	$\mathrm{T}_{\mathtt{stg}}$	$-55 \sim +125$		

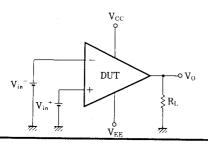
# $\blacksquare \ \ Electrical \ Characteristics \ \ (V_{\text{CC}}\!=\!15V, \ \ V_{\text{EE}}\!=\!-15V, \ \ Ta\!=\!25\%)$

Item	Symbol	Test Circuit	Condition	min.	typ.	max.	Unit
Input Offset Voltage	V <sub>I(offset)</sub>	1	$R_s \leq 10 k\Omega$		0.5	6	mV
Input Offset Current	I <sub>IO</sub>	1			5	200	nA
Input Bias Current	IBias	1				500	nA
Voltage Gain	Gv	1	$R_L \ge 2k\Omega$ , $V_0 = \pm 10V$	86	100		dB
Maximum Output Voltage	V	2	$R_L \ge 10 k\Omega$	±12	±14		V
	V <sub>O(max.)</sub>		$R_L \ge 2k\Omega$	±10	±13		V
Common-Mode Input Voltage Width	V <sub>CM</sub>	3		±12	±14		V
Common-Mode Rejection Ratio	CMR	1		70	90		đВ
Supply Voltage Rejection Ratio	SVR	1			30	150	μV/V
Power Consumption	Pc	4	$R_L = \infty$		90	170	mW
Slew Rate	SR	5	$R_L \ge 2k\Omega$		2.0		V/μs
Input Referred Noise Voltage	Vni	6	$R_s=1k\Omega$ , $B=10Hz\sim30kHz$		2.5		$\mu V_{rms}$

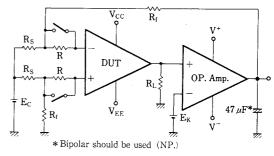
### **■** Pin Connection



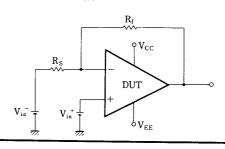
 $\textbf{Test Circuit 2} \ (V_{O(\text{max.})})$ 



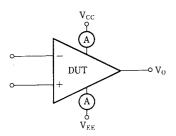
 $\begin{array}{lll} \textbf{Test Circuit 1} & (V_{I(offset)}, I_{IO}, \ I_{Bias}, G_V, CMR, SVR) \end{array}$ 



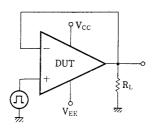
Test Circuit 3  $(V_{CM})$ 



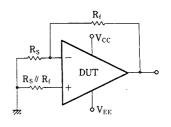
Test Circuit 4 (Pc)

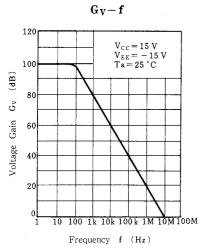


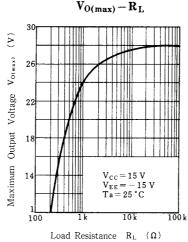
Test Circuit 5 (SR)

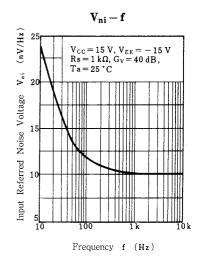


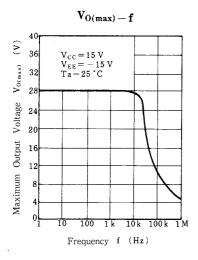
Test Circuit 6 (Vni)

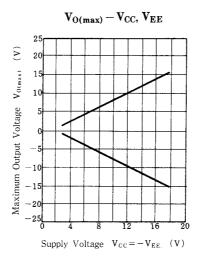


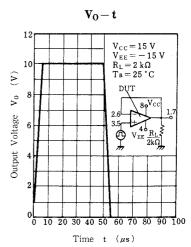






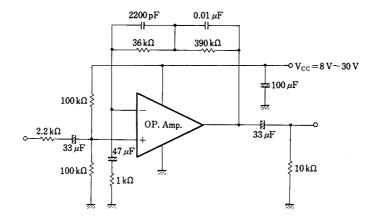






## ■Application Circuit

## RIAA Pre-Amp. (Single Voltage Operation)



### ■ Pin

Pin No.	Pin Name				
1	Ch. 1 Output				
2	Ch. 1 Invert Input				
3	Ch. 1 Non Invert Input				
4	$V_{EE}$				
5	Ch. 2 Non Invert Input				
6	Ch. 2 Invert Input				
7	Ch. 2 Output				
8	Vcc				

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